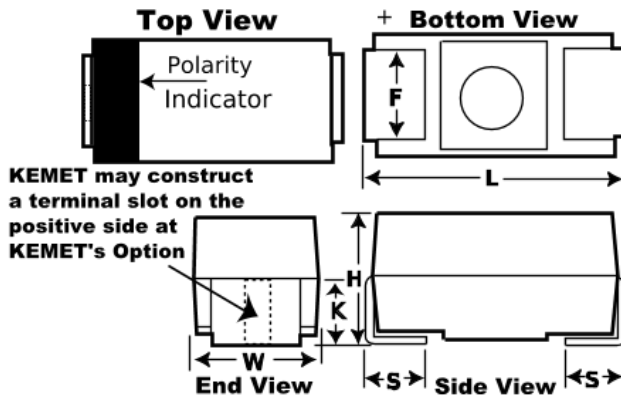


T495T336M006ZTE800

Obsolete

Tantalum, MnO₂ Tantalum, 33 uF, 20%, 6.3 VDC, SMD, Molded, Low Profile, Low ESR, Surge Robust, 800 mOhms, 3528, 1.2mm



Dimensions

Footprint	3528
L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
H	1.2mm MAX
S	0.8mm +/-0.3mm
F	2.2mm +/-0.1mm
K	1mm TYP

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	2500

General Information

Dielectric	MnO ₂ Tantalum
Style	SMD Chip
Description	SMD, Molded, Low Profile, Low ESR, Surge Robust
Features	Low Profile, Low ESR, Surge Robust
RoHS	Yes
Termination	Tin
AEC-Q200	No
Notes	Obsolete. Old Part Number [Obsolete] Was B45190R1336M209.

Specifications

Capacitance	33 uF
Capacitance Tolerance	20%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6%
Failure Rate	N/A
ESR	0.8 Ohms (100kHz)
Ripple Current	310 mAmps (25C), 279 mAmps (85C), 124 mAmps (125C)
Leakage Current	2.1 uA